



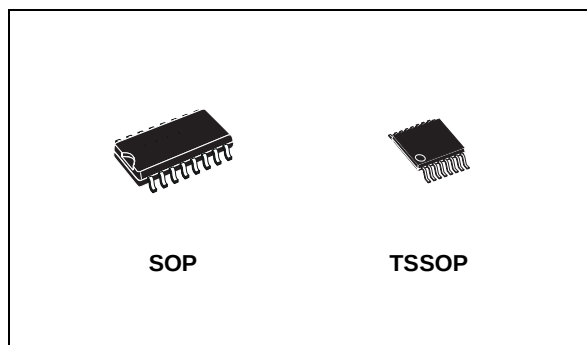
STLVDS32

HIGH SPEED DIFFERENTIAL LINE RECEIVERS

- MEETS OR EXCEEDS THE REQUIREMENTS OF ANSI TIA/EIA-644 STANDARD
- OPERATES WITH A SINGLE 3.3V SUPPLY
- DESIGNED FOR SIGNALING RATE UP TO 400Mbps
- DIFFERENTIAL INPUT THRESHOLDS $\pm 100\text{mV}$ MAX
- TYPICAL PROPAGATION DELAY TIME OF 2.5ns
- POWER DISSIPATION 60mW TYPICAL PER RECEIVER AT 200MHz
- LOW VOLTAGE TTL (LVTTL) LOGIC OUTPUT LEVELS
- PIN COMPATIBLE WITH THE AM26LS32, SN65LVD32
- OPEN CIRCUIT FAIL SAFE
- ESD PROTECTION:
7KV RECEIVER PINS
3KV ALL PINS VS GND

DESCRIPTION

The STLVDS32 is a differential line receiver that implements the electrical characteristics of low voltage differential signaling (LVDS). This signaling technique lowers the output voltage levels of 5V differential standard levels (such as TIA/EIA-422B) to reduce the power, increase the switching speeds and allow operations with a 3.3V supply rail. This differential receiver provides a



valid logical output state with a 3.3V supply rail. It also provides a valid logical output state with a $\pm 100\text{mV}$ differential input voltage within the input common mode voltage range. The input common mode voltage allows 1V of ground potential difference between two LVDS nodes.

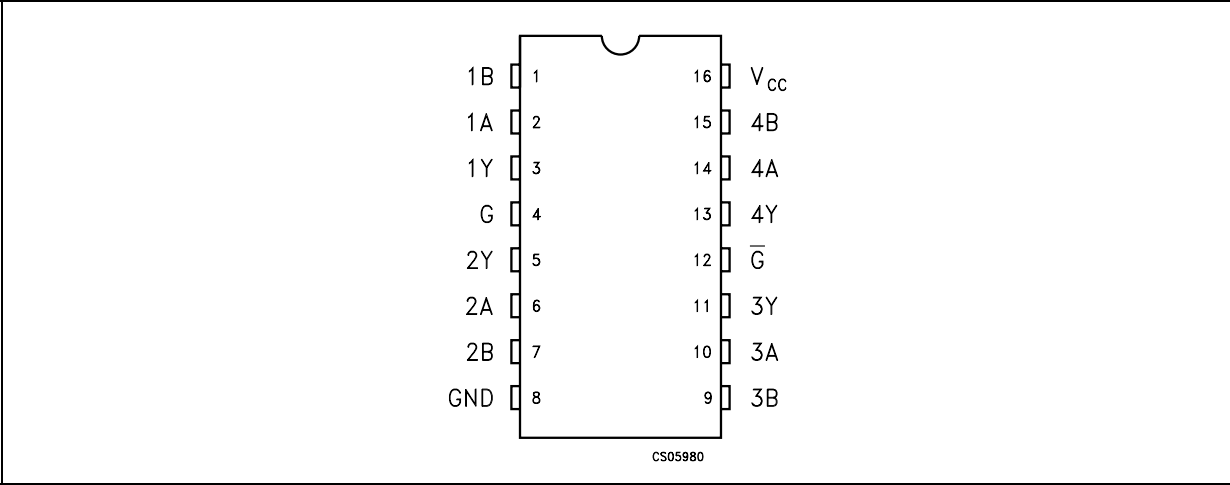
The intended application of this device and signalling technique is both point-to-point and multidrop data transmission over controlled impedance media approximately 100Ω . The transmission media may be printed circuit board traces, backplanes or cables. The ultimate rate and distance of data transfer depend upon the attenuation characteristics of the media and noise coupling to the environment.

The STLVDS32 version is characterized for operation from -40°C to 85°C .

ORDERING CODES

Type	Temperature Range	Package	Comments
STLVDS32BD	-40 to 85 °C	SO-16 (Tube)	50parts per tube / 20tube per box
STLVDS32BDR	-40 to 85 °C	SO-16 (Tape & Reel)	2500 parts per reel
STLVDS32BTR	-40 to 85 °C	TSSOP16 (Tape & Reel)	2500 parts per reel

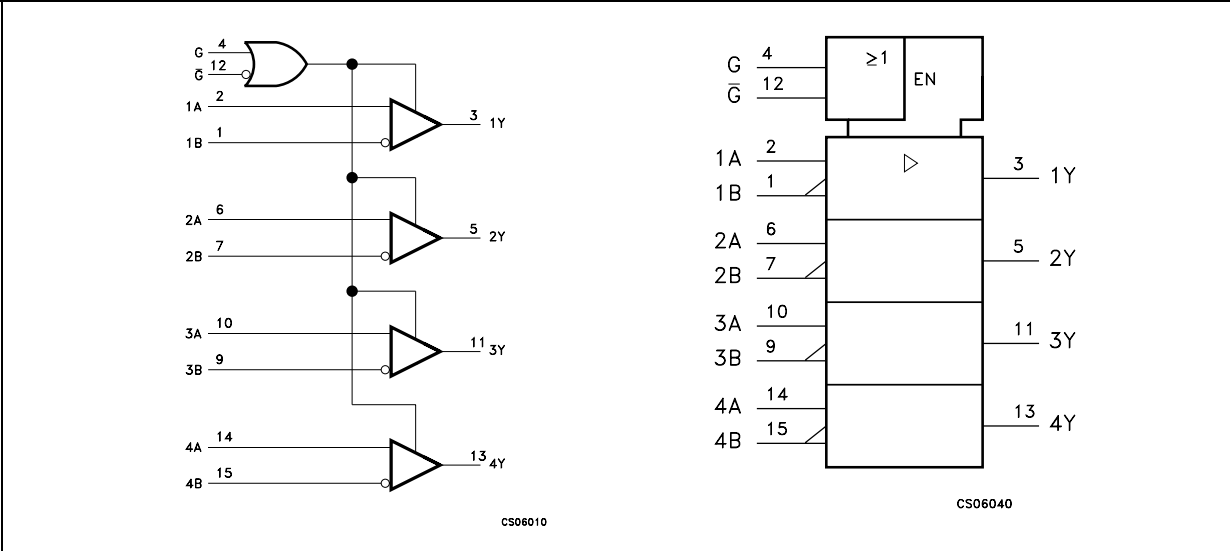
PIN CONFIGURATION



PIN DESCRIPTION

PIN N°	SYMBOL	NAME AND FUNCTION
2, 6, 10, 14	1A to 4A	Receiver Inputs
1, 7, 9, 15	1B to 4B	Negated Receiver Inputs
3, 5, 11, 13	1Y to 4Y	Receiver Outputs
4	G	Enable
12	G̅	Enable
8	GND	Ground
16	V _{CC}	Supply Voltage

LOGIC DIAGRAM AND LOGIC SYMBOL



TRUTH TABLE

DIFFERENTIAL INPUTS	ENABLES		OUTPUT
A, B	G	$\overline{G}$	Y
$V_{ID} \geq 100\text{mV}$	H	X	H
	X	L	H
$-100\text{mV} < V_{ID} < 100\text{mV}$	H	X	?
	X	L	?
$V_{ID} \leq -100\text{mV}$	H	X	L
	X	L	L
X	L	H	Z
OPEN	H	X	H
	X	L	H

L = Low level, H = High Level, X = Don't care, Z = High Impedance, ? = Indeterminate

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V_{CC}	Supply Voltage (Note 1)		-0.5 to 4.6	V
V_I	Input Voltage		-0.5 to ($V_{CC} + 0.5$)	V
V_I	Input Voltage (A or B inputs)		-0.5 to 4.6	V
ESD	Human Body Model	Pins Receivers	7	KV
		All Pins vs GND	3	
T_{stg}	Storage Temperature Range		-65 to +150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

Note 1: All voltages except differential I/O bus voltage, are with respect to the network ground terminal.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{CC}	Supply Voltage	3.0	3.3	3.6	V
V_{IH}	HIGH Level Input Voltage (ENABLE)	2.0			V
V_{IL}	LOW Level Input Voltage (ENABLE)			0.8	V
$ V_{ID} $	Magnitude of Differential Input Voltage	0.1		0.6	V
V_{IC}	Common Mode Input Voltage	0.5 $ V_{ID} $		2.4-0.5 $ V_{ID} $	V
				$V_{CC} - 0.8$	
T_A	Operating Temperature Range	-40		85	°C

ELECTRICAL CHARACTERISTICS (Over recommended operating conditions unless otherwise noted.
All typical values are at $T_A = 25^\circ\text{C}$, and $V_{CC} = 3.3\text{V}$)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_{ITH+}	Positive Going Differential Input Voltage Threshold				100	mV
V_{ITH-}	Negative Going Differential Input Voltage Threshold		-100			mV
V_{OH}	High Level Output Voltage	$I_{OH} = -8\text{mA}$	2.4			V
		$I_{OH} = -4\text{mA}$	2.8			
V_{OL}	Low Level Output Voltage	$I_{OH} = 8\text{mA}$			0.4	V
I_{CC}	Supply Current	Enabled, No Load		10	18	mA
		Disabled		0.25	0.5	
I_I	Input Current (A or B inputs)	$V_I = 0\text{V}$	-2	-10	-20	μA
		$V_I = 2.4\text{V}$	-1.2	-3		
$I_{I(OFF)}$	Power off Input Current (A or B inputs)	$V_{CC} = 0$ $V_I = 3.6\text{V}$		10	20	μA
I_{IH}	High Level Input Current (EN, G, $\bar{G}$ or Inputs)	$V_{IH} = 2\text{V}$			10	μA
I_{IL}	Low Level Input Current (EN, G, $\bar{G}$ or Inputs)	$V_{IL} = 0.8\text{V}$			10	μA
I_{OZ}	High Impedance Output Current	$V_O = 0$ or V_{CC}			± 10	μA

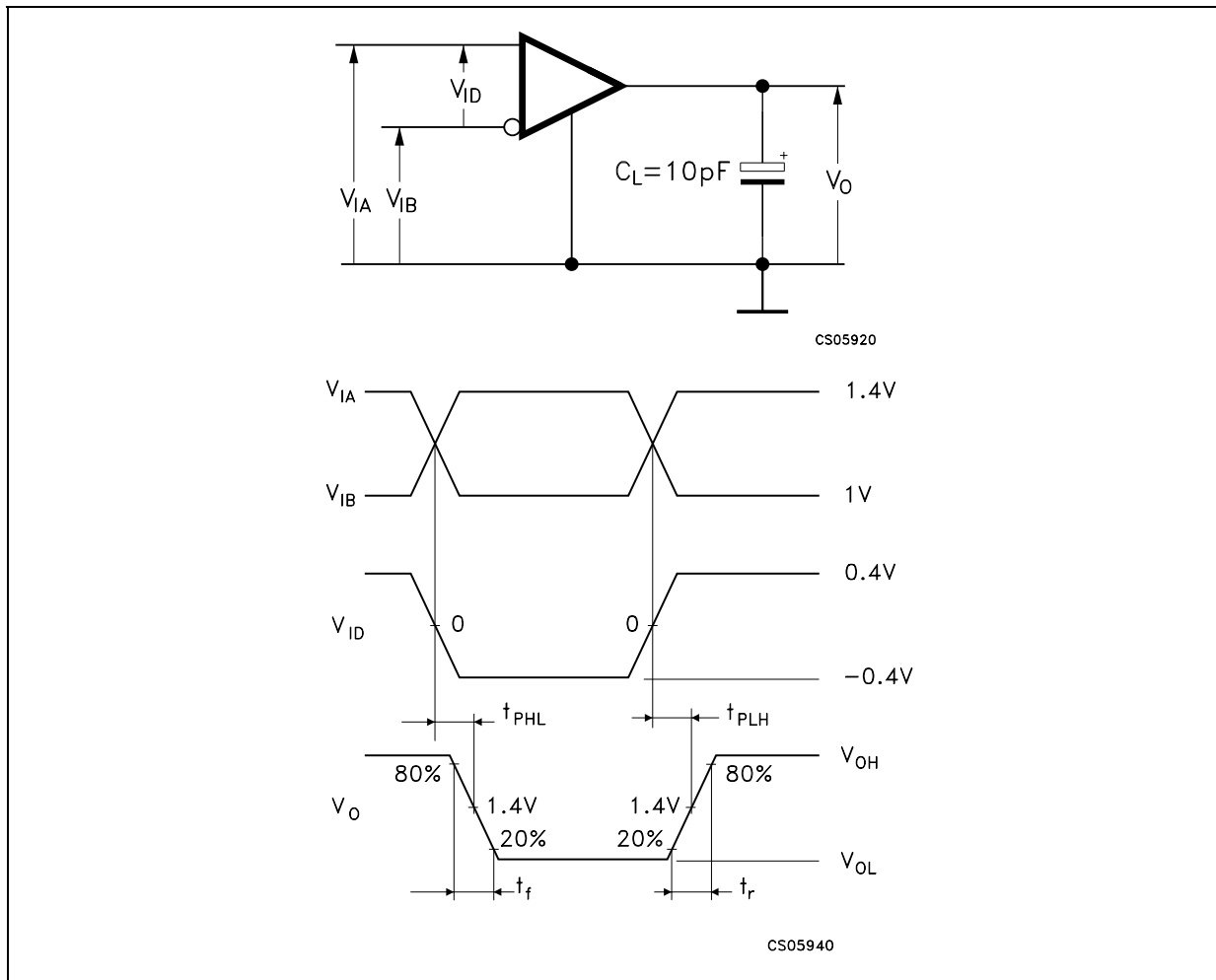
SWITCHING CHARACTERISTICS (Unless otherwise noted. Typical values are referred to $T_A = 25^\circ\text{C}$ and $V_{CC} = 3.3\text{V}$)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
t_{PLH}	Propagation Delay Time, Low to High Output	$C_L = 10\text{pF}$ Fig. 1	1.5	2.5	3.3	ns
t_{PHL}	Propagation Delay Time, High to Low Output		1.5	2.5	3.3	ns
t_r	Differential Output Signal Rise Time			0.4		ns
t_f	Differential Output Signal Fall Time			0.4		ns
$t_{sk(O)}$	Channel to Channel Output Skew (note1)			0.1	0.3	ns
$t_{sk(P)}$	Pulse Skew ($ t_{PHL} - t_{PLH} $) (note2)			0.2	0.4	ns
$t_{sk(PP)}$	Part to Part Skew (note3)				1	ns
t_{PZH}	Propagation Delay Time, High Impedance to High Level Output	Fig. 2		3	12	ns
t_{PZL}	Propagation Delay Time, High Impedance to Low Level Output			5	12	ns
t_{PHZ}	Propagation Delay Time, High Level to High Impedance Output			5	12	ns
t_{PLZ}	Propagation Delay Time, Low Level to High Impedance Output			5	12	ns

Note 1: $t_{sk(O)}$ is the maximum delay time difference between the propagation delay of one channel and that of the others on the same chip with any event on the inputs.

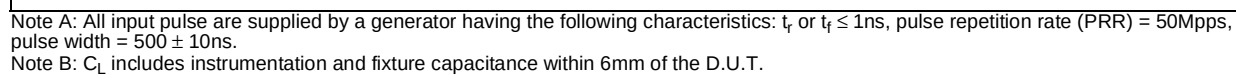
Note 2: $t_{sk(P)}$ is the magnitude difference in differential propagation delay time between the positive going edge and the negative going edge of the same channel.

Note 3: $t_{sk(PP)}$ is the differential channel-to-channel skew of any event between devices. This specification applies to devices at the same V_{CC} , and within 5°C of each other within the operating temperature range.

Figure 1 : Timing Test Circuit, Timing And Waveforms

Note A: All input pulse are supplied by a generator having the following characteristics: t_r or $t_f \leq 1\text{ns}$, pulse repetition rate (PRR) = 50Mpps, pulse width = $10 \pm 0.2\text{ns}$.

Note B: C_L includes instrumentation and fixture capacitance within 6mm of the D.U.T.



TYPICAL PERFORMANCE CHARACTERISTICS (unless otherwise specified $T_j = 25^\circ\text{C}$)

Figure 3 : Output Current vs Output Voltage

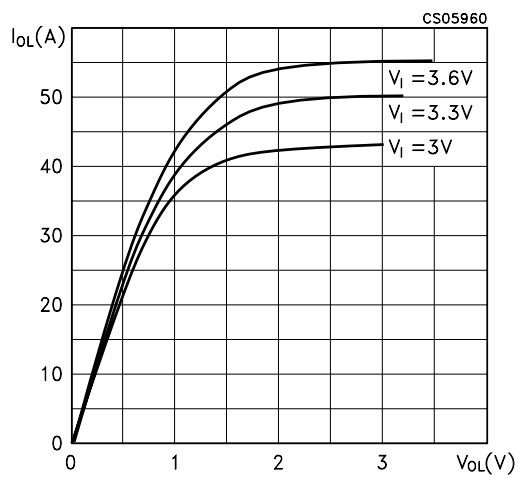
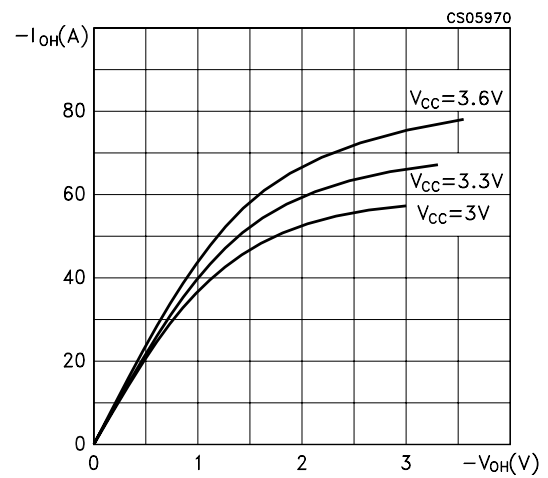
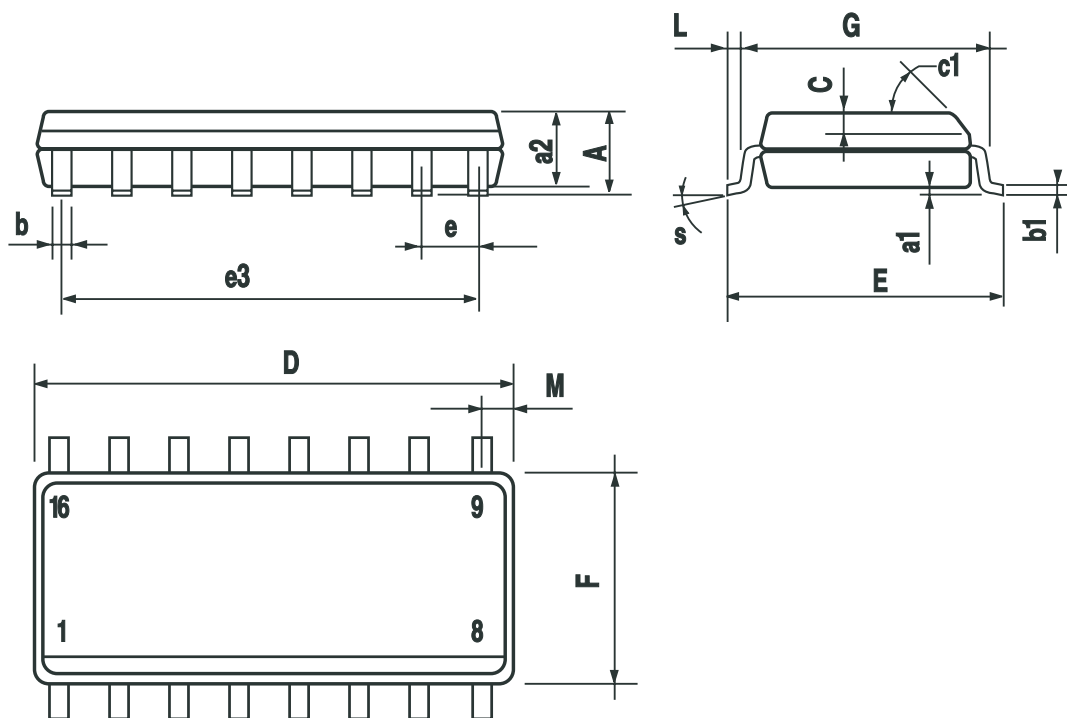


Figure 4 : Output Current vs Output Voltage



SO-16 MECHANICAL DATA

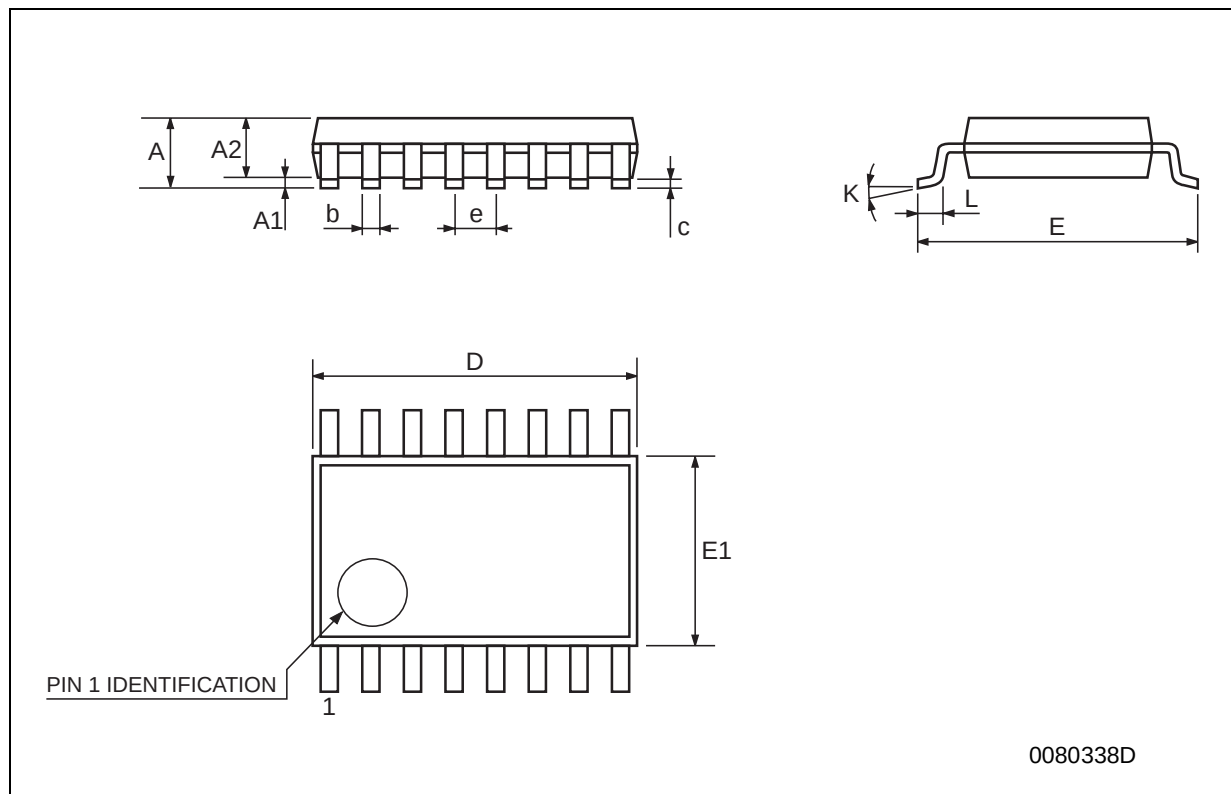
DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.004		0.008
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45° (typ.)					
D	9.8		10	0.385		0.393
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.62			0.024
S	8° (max.)					



PO13H

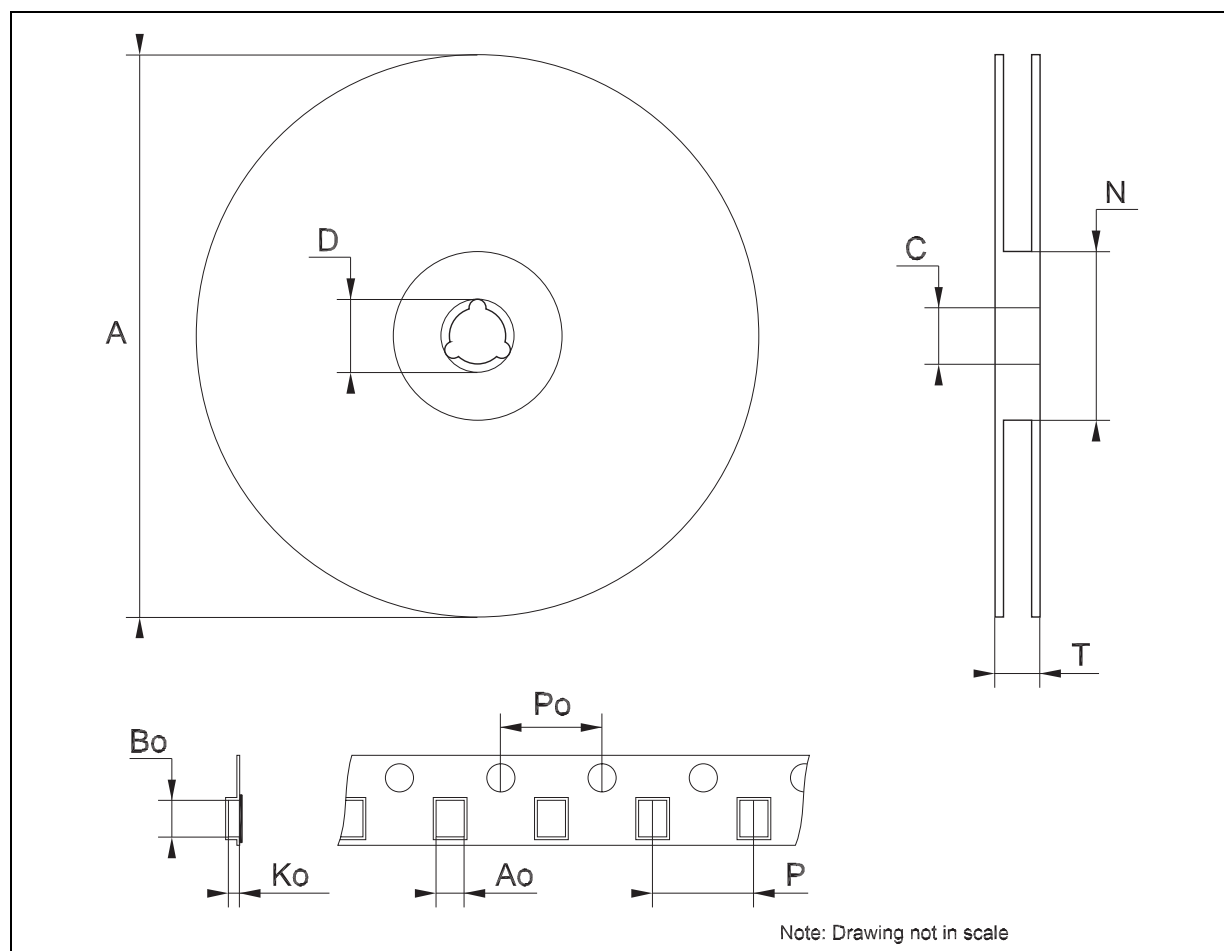
TSSOP16 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.0079
D	4.9	5	5.1	0.193	0.197	0.201
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
e		0.65 BSC			0.0256 BSC	
K	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030



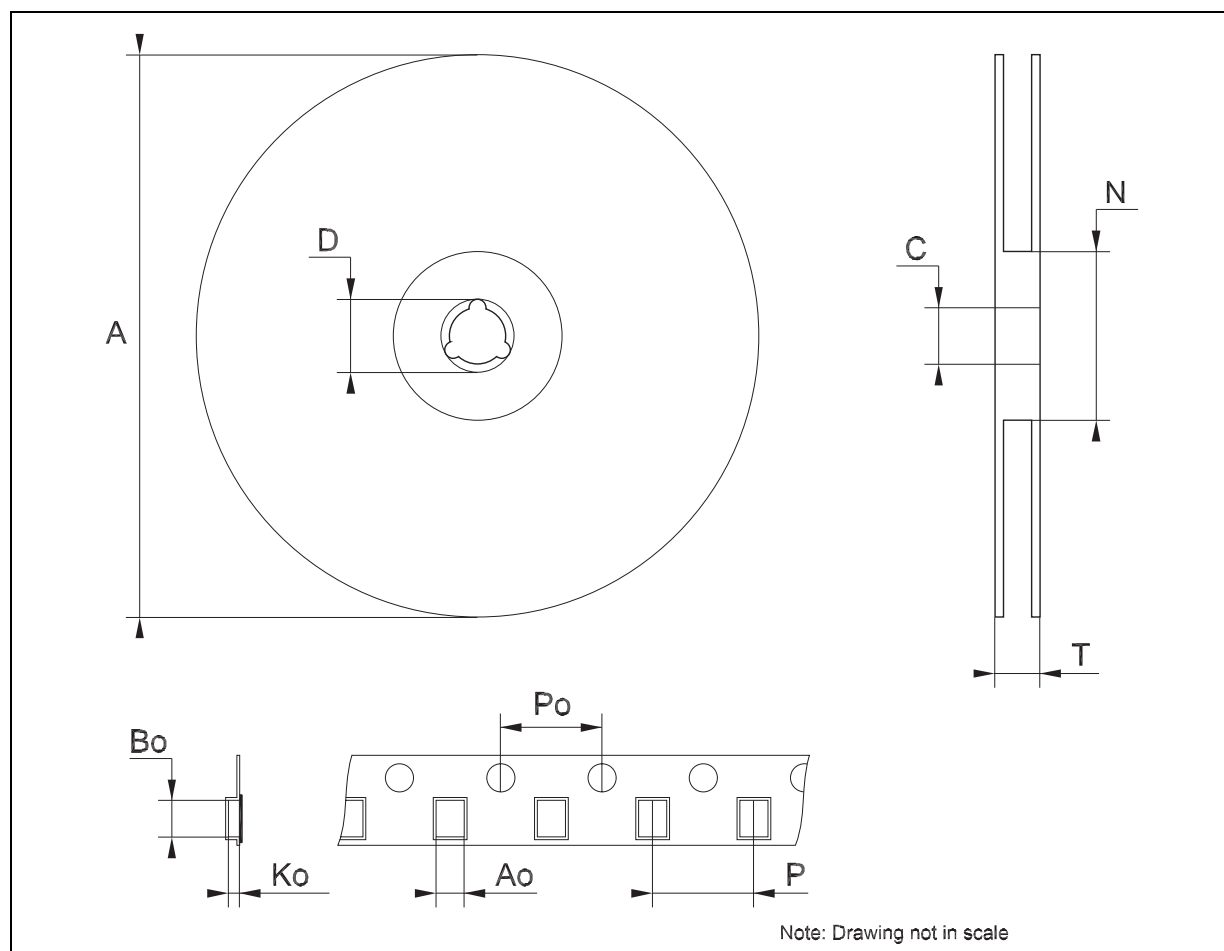
Tape & Reel SO-16 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			330			12.992
C	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
T			22.4			0.882
Ao	6.45		6.65	0.254		0.262
Bo	10.3		10.5	0.406		0.414
Ko	2.1		2.3	0.082		0.090
Po	3.9		4.1	0.153		0.161
P	7.9		8.1	0.311		0.319



Tape & Reel TSSOP16 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			330			12.992
C	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
T			22.4			0.882
Ao	6.7		6.9	0.264		0.272
Bo	5.3		5.5	0.209		0.217
Ko	1.6		1.8	0.063		0.071
Po	3.9		4.1	0.153		0.161
P	7.9		8.1	0.311		0.319



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